# Your Partner for Semiconductor Process Control



# **ZEISS OEM Spectrometers**

Working in concert with you we develop superior OEM spectroscopy solutions upon proven ZEISS technology and expertise



Seeing beyond

www.zeiss.com/spectrometer-modules

# **Our Technology is Your Solution**

Using ZEISS spectrometers for process can give you the edge when developing your OEM solutions. Take advantage of proven ZEISS technology, which can be completely tailored to your needs.

# **ZEISS as OEM Supplier – Applications**



#### **Etching Process Control**

ZEISS spectrometers are ideally suited for the end-point detection and thickness monitoring of etching processes via Optical Emission Spectroscopy (OES), Ellipsometry or Spectral Reflectometry.



#### **CMP Process Control**

ZEISS develops customized spectrometer solutions for the Chemical Mechanical Polishing (CMP) monitoring of wafers via high-end thickness measurements.



#### **Critical Dimension Metrology**

ZEISS Spectrometers enable the metrology of CD variations of die structures on a wafer via optical scatterometry (OCD).

# **ZEISS Spectrometers – Your benefits**

- Highest Wafer Throughput due to minimal integration time
- Fast Scalability for Volume Production
- Small tool-to-tool Variability
- Long-term Stability & Calibration
- Customized Spectrometers with ZEISS Abberation Corrected Gratings and various Detector / Slit-Size Options



Get in touch to start the conversation

Simply scan the code for more information

## MCS-PDA

Wavelength range	190–1015 nm
Optical Input	SMA*
Numerical Aperture	0.22
Spectral Pixel pitch	0.8 nm
Straylight	< 0.1 % (at 340 nm)
Detector	S 3904-1024Q (1024 px)*
SNR	> 12,000
DNR	> 23,000
Integration time	> 1.1 ms
	*others avaiable on request



## MCS-CCD

Wavelength range	190–980 nm
Optical Input	SMA*
Numerical Aperture	0.22
Spectral Pixel pitch	0.8 nm
Straylight	< 0.1 % (at 340 nm)
Detector	S 7031-1006 (1044 x 64 px)*
SNR	> 1,000
DNR	> 32,000
Integration time	> 3 ms

<sup>\*</sup>others avaiable on request



# CGS-CCD

Wavelength range	190–1015 nm	
Optical Input	SMA*	
Numerical Aperture	0.22	
Spectral Pixel pitch	0.4 nm	
Straylight	< 0.1 % (at 240 nm)	
Detector	S 11156 (2048 px)*	
SNR	> 500	
DNR	> 8,600	
Integration time	> 0.1 ms	

\*others avaiable on request



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